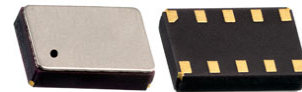


# DTCXO Temperature Compensated Real-Time-Clock Module with SPI bus



3.7 x 2.5 x 0.9 mm

AB-RTCMC-32.768kHz-EOA9-S3



RoHS/RoHS II compliant

Moisture Sensitivity Level: MSL=1

## FEATURES:

- With state-of-the-art RTC Technology by Micro Crystal AG
- RTC module with built-in “Tuning Fork” crystal oscillating at 32.768 kHz
- Factory calibrated, all built-in Temperature Compensation circuitry Time accuracy Option A & B. See Part Identification on page 7 for details
- Ultra low power consumption: 800nA typ @ VDD = 3.0V / Tamb = 25°C
- Wide clock operating voltage: 1.3 – 5.5V
- Wide interface operating voltage: 1.4 – 5.5V
- Extended operating temperature range: -40°C to +125°C
- SPI serial interface with fast mode SCL clock frequency of 1 MHz
- Provides year, month, day, weekday, hours, minutes and seconds
- Highly versatile alarm and timer functions
- Integrated Low-Voltage Detector, Power-On Reset and Self-Recovery System
- Main Power Supply to Backup Battery switchover circuitry with Trickle Charger
- Programmable CLKOUT pins for peripheral devices (32.768 kHz / 1024 Hz / 32 Hz / 1 Hz)
- Small and compact package size: 3.7 x 2.5 x 0.9 mm. RoHS-compliant and 100% leadfree

## APPLICATIONS:

- Wide range in communication & measuring equipment
- Commercial & Industrial applications
- Automotive electronics applications
- Wireless communications
- PDA and Palm Pilots
- Credit Cards with Security Technology

## STANDARD SPECIFICATIONS:

### Absolute Maximum Ratings

Parameters	Min.	Typ.	Max.	Units	Notes
Supply Voltage (V <sub>DD</sub> )	GND-0.3		+6.0	V	>GND / <V <sub>DD</sub>
Supply Current (I <sub>DD</sub> ; I <sub>SS</sub> )	-50		+50	mA	V <sub>DD</sub> Pin
Input Voltage (V <sub>I</sub> )	GND-0.3		V <sub>DD</sub> +0.3	V	Input Pin
Output Voltage (V <sub>O</sub> )	GND-0.5		V <sub>DD</sub> +0.5	V	$\overline{\text{INT}}$ / CLKOUT
DC Input Current (I <sub>I</sub> )	-10		+10	mA	
DC Output Current (I <sub>O</sub> )	-10		+10	mA	
Total Power Dissipation (P <sub>TOT</sub> )			300	mW	
Operating Temperature Range (T <sub>OPR</sub> )	-40		+125	°C	
Storage Temperature (T <sub>STO</sub> )	-55		+125	°C	Stored as bare product

### Frequency and Time Characteristics

V<sub>DD</sub>=3.0V; V<sub>SS</sub>=0V; T<sub>AMB</sub>=+25°C; f<sub>OSC</sub>=32.768kHz

Parameters	Min.	Typ.	Max.	Units	Notes
<b>32.768kHz Oscillator Characteristics</b>					
Frequency Accuracy ( $\Delta F/F$ )		±10	±20	ppm	F <sub>CLKOUT</sub> =32.768kHz; T <sub>AMB</sub> =+25°C; V <sub>DD</sub> =3.0V
Frequency vs Voltage ( $\Delta F/V$ )		±0.5	±1.0	ppm/V	T <sub>AMB</sub> =+25°C; V <sub>DD</sub> =1.4~5.5V
Frequency vs Temperature ( $\Delta F/T_{OPR}$ )	-0.035ppm/°C <sup>2</sup> (T <sub>OPR</sub> -T <sub>O</sub> ) <sup>2</sup> ±10%			ppm	T <sub>OPR</sub> =-40~+125°C; V <sub>DD</sub> =3.0V
Turnover Temperature (T <sub>O</sub> )	+20	+25	+30	°C	
Aging (first year)	-3		+3	ppm	T <sub>AMB</sub> =+25°C
Start-up Time Voltage (V <sub>START</sub> )					
Start-up Time (T <sub>START</sub> )		0.5	3	s	T <sub>AMB</sub> =-40 ~ +85°C
		1	3		T <sub>AMB</sub> =-40 ~ +125°C
CLKOUT duty cycle	40	50	60	%	F <sub>CLKOUT</sub> =32.768kHz; T <sub>AMB</sub> =+25°C

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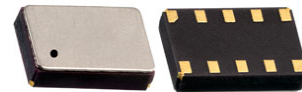
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Revised: 02.05.13

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# DTCXO Temperature Compensated Real-Time-Clock Module with SPI bus



3.7 x 2.5 x 0.9 mm

AB-RTCMC-32.768kHz-EOA9-S3



RoHS/RoHS II compliant

(Continued)

Parameters		Min.	Typ.	Max.	Units	Notes
<b>Time accuracy, DTCXO Digitally Temperature Compensated</b>						
Time Accuracy Option: A ( $\Delta t/t$ )	$T_{AMB}=+25^{\circ}\text{C}$		$\pm 1$	$\pm 3$	ppm	
	$T_{AMB}=0 \sim +50^{\circ}\text{C}$		$\pm 2$	$\pm 4$		
	$T_{AMB}=-10 \sim +65^{\circ}\text{C}$		$\pm 3$	$\pm 5$		
	$T_{AMB}=-40 \sim +85^{\circ}\text{C}$		$\pm 4$	$\pm 6$		
	$T_{AMB}=-40 \sim +125^{\circ}\text{C}$		$\pm 5$	$\pm 8$		
Time Accuracy Option: B ( $\Delta t/t$ )	$T_{AMB}=+25^{\circ}\text{C}$		$\pm 1$	$\pm 3$	ppm	
	$T_{AMB}=0 \sim +50^{\circ}\text{C}$		$\pm 3$	$\pm 5$		
	$T_{AMB}=-10 \sim +65^{\circ}\text{C}$		$\pm 5$	$\pm 10$		
	$T_{AMB}=-40 \sim +85^{\circ}\text{C}$		$\pm 10$	$\pm 25$		
	$T_{AMB}=-40 \sim +125^{\circ}\text{C}$		$\pm 15$	$\pm 30$		

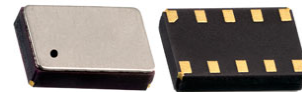
## Static Characteristics

$V_{DD}=1.4\sim 5.5\text{V}$ ;  $V_{SS}=0\text{V}$ ;  $T_{AMB}=-40^{\circ}\text{C} \sim +125^{\circ}\text{C}$ ;  $f_{OSC}=32.768\text{kHz}$

Parameters		Min.	Typ.	Max.	Units	Notes
<b>Supplies</b>						
Supply Voltage ( $V_{DD}$ )		1.4		5.5	V	Time-keeping mode $I^2C$ bus reduced speed
		2.1		5.5		$I^2C$ bus full speed
Minimum Supply Voltage Detection ( $V_{LOW1}$ )		1.8		2.1	V	$T_{AMB}=-40 \sim +125^{\circ}\text{C}$
Minimum Supply Voltage Detection ( $V_{LOW2}$ )		1.0		1.4	V	$T_{AMB}=-40 \sim +125^{\circ}\text{C}$
Main Supply to Backup Supply Switchover Hysteresis ( $V_{HYST}$ )			20		mV	$V_{DD}$ to $V_{BACK} = 3.0\text{V}$
Supply Current $I_{DD}$ ( $V_{BACK}=0\text{V}$ ) or $I_{BACK}$ ( $V_{DD}=0\text{V}$ )	$V_{DD}=1.4\text{V}$ $T_{AMB}=-40^{\circ}\text{C} \sim +85^{\circ}\text{C}$		0.6	1.5	$\mu\text{A}$	SPI bus inactive CLKOUT disabled $V_{BACK}=0\text{V}$ Or $V_{DD}=0\text{V}$
	$V_{DD}=1.4\text{V}$ $T_{AMB}=-40^{\circ}\text{C} \sim +125^{\circ}\text{C}$			4.6		
	$V_{DD}=3.3\text{V}$ $T_{AMB}=-40^{\circ}\text{C} \sim +85^{\circ}\text{C}$		0.8	2.0		
	$V_{DD}=3.3\text{V}$ $T_{AMB}=-40^{\circ}\text{C} \sim +125^{\circ}\text{C}$			5.2		
	$V_{DD}=5.0\text{V}$ $T_{AMB}=-40^{\circ}\text{C} \sim +85^{\circ}\text{C}$		0.9	2.2		
	$V_{DD}=5.0\text{V}$ $T_{AMB}=-40^{\circ}\text{C} \sim +125^{\circ}\text{C}$			5.5		



# DTCXO Temperature Compensated Real-Time-Clock Module with SPI bus



3.7 x 2.5 x 0.9 mm

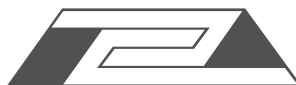
AB-RTCMC-32.768kHz-EOA9-S3



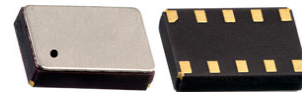
RoHS/RoHS II compliant

(Continued)

Parameters		Min.	Typ.	Max.	Units	Notes
Supply Current ( $I_{DD}$ )	SCL= 200kHz $V_{DD}$ = 1.4V $T_{AMB}$ = -40°C ~ +85°C			14	$\mu$ A	SPI bus active CLKOUT disabled
	SCL= 200kHz $V_{DD}$ = 1.4V $T_{AMB}$ = -40°C ~ +125°C			18		
	SCL= 1MHz $V_{DD}$ = 3.3V $T_{AMB}$ = -40°C ~ +85°C			50		
	SCL= 1MHz $V_{DD}$ = 3.3V $T_{AMB}$ = -40°C ~ +125°C			55		
	SCL= 1MHz $V_{DD}$ = 5.0V $T_{AMB}$ = -40°C ~ +85°C			65		
	SCL= 1MHz $V_{DD}$ = 5.0V $T_{AMB}$ = -40°C ~ +125°C			75		
Current Consumption ( $I_{DD32K}$ )	$V_{DD}$ =5.0V		2.5	3.4	$\mu$ A	SPI bus inactive CLKOUT =32.768kHz $C_{LOAD}$ =7.5pF
	$V_{DD}$ =3.3V		1.5	2.2		
	$V_{DD}$ =1.4V		1.1	1.6		
<b>Input</b>						
LOW Level Input Voltage ( $V_{IL}$ )				20%* $V_{DD}$	V	$V_{DD}$ = 1.4 ~ 5.5 $V_{DD}$ Pins:SCL,SDI,CLKOE,CE
HIGH Level Input Voltage ( $V_{IH}$ )		80%* $V_{DD}$			V	
Input Leakage Current ( $I_L$ )	$T_{amb}$ =-40 ~+85°C	-1		+1	$\mu$ A	$V_{SS}>V_I<V_{DD}$
	$T_{amb}$ =-40 ~+125°C	-1.5		+1.5		
Input Capacitance ( $C_I$ )				7	pF	



# DTCXO Temperature Compensated Real-Time-Clock Module with SPI bus



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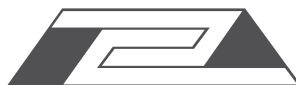
AB-RTCMC-32.768kHz-EOA9-S3



RoHS/RoHS II compliant

(Continued)

Parameters		Min.	Typ.	Max.	Units	Notes
<b>Output</b>						
HIGH Level Output Voltage ( $V_{OH}$ )	$V_{DD} = 1.4V; I_{OH} = 0.1mA$	1.0			V	
	$V_{DD} = 3.3V; I_{OH} = 1.5mA$	2.7				
	$V_{DD} = 5.0V; I_{OH} = 2.0mA$	4.5				
LOW Level Output Voltage ( $V_{OL}$ )	$V_{DD} = 1.4V; I_{OL} = 0.4mA$			0.2	V	
	$V_{DD} = 3.3V; I_{OL} = 1.5mA$			0.25		
	$V_{DD} = 5.0V; I_{OL} = 5.0mA$			0.8		
HIGH Level Output Current ( $I_{OH}$ )	$V_{OH} = 4.5V / V_{DD} = 5V$			2.0	mA	
LOW Level Output Current ( $I_{OL}$ )	$V_{OL} = 0.8V / V_{DD} = 5V$			-5.0	mA	
Output Leakage Current ( $I_{LO}$ )	$V_O = V_{DD} \text{ OR } V_{SS}$ $T_{AMB} = -40^{\circ}C \sim +85^{\circ}C$	-1	0	+1	$\mu A$	
	$V_O = V_{DD} \text{ OR } V_{SS}$ $T_{AMB} = -40^{\circ}C \sim +125^{\circ}C$	-1.5	0	+1.5		
<b>Operating Temperature Range</b>						
Operating Temperature Range ( $T_{OPR}$ )		-40		+125	$^{\circ}C$	
<b>EEPROM Characteristics</b>						
Read Voltage ( $V_{Read}$ )	$T_{AMB} = -40^{\circ}C \sim +125^{\circ}C$	1.4			V	
Programming Voltage ( $V_{Prog}$ )	$T_{AMB} = -40^{\circ}C \sim +125^{\circ}C$	2.2			V	
EEPROM Programming Time ( $T_{Prog}$ )	$T_{AMB} = -40^{\circ}C \sim +125^{\circ}C$ 1 Byte EEPROM User			35	ms	
	$T_{AMB} = -40^{\circ}C \sim +125^{\circ}C$ 1 Byte EEPROM Control			100		
	$T_{AMB} = -40^{\circ}C \sim +125^{\circ}C$ 2-4 Byte EEPROM Control			135		
EEPROM Write/Erase Cycles ( $V_{HYST}$ )	$V_{DD} \text{ to } V_{BACK} = 3.0V$	5000			Cycles	

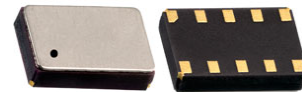


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AB-RTCMC-32.768kHz-EOA9-S3



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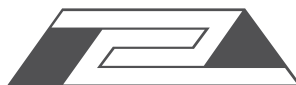
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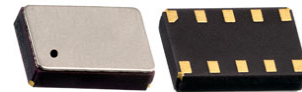
Parameters		Min.	Typ.	Max.	Units	Notes
<b>Trickle Charger</b>						
Current Limiting Resistors	R80K		80		kΩ	V <sub>DD</sub> = 5.0V V <sub>BACK</sub> = 3.0V T <sub>AMB</sub> = 25°C
	R20k		20			
	R5k		5			
	R1.5k		1.5			
<b>Thermometer</b>						
Thermometer Precision (T <sub>E</sub> )	T <sub>AMB</sub> = -40°C ~ +85°C		±4		°C	
	T <sub>AMB</sub> = -40°C ~ +125°C		±6			

## SPI Interface Dynamic Characteristics

V<sub>SS</sub>=0V; T<sub>AMB</sub>=-40°C ~+125°C; All timing values are valid within the operating supply voltage range and references to V<sub>IL</sub> and V<sub>IH</sub> with an input voltage swing from V<sub>SS</sub> and V<sub>DD</sub>.

Parameters	Symbol	Notes	V <sub>DD</sub> =1.6V		V <sub>DD</sub> =2.4V		V <sub>DD</sub> =3.3V		V <sub>DD</sub> =5.0V		Units
			Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
SCL Clock Frequency	f <sub>clk(SCL)</sub>			0.2		0.6		1.0		1.0	MHz
SCL Time	t <sub>SCL</sub>		5		1.7		1		1		μs
Clock HIGH Time	t <sub>clk(H)</sub>		1500		700		400		400		ns
Clock LOW Time	t <sub>clk(L)</sub>		1500		700		400		400		ns
Rise Time	t <sub>r</sub>	For SCL signal		800		800		200		200	ns
Fall Time	t <sub>f</sub>	For SCL signal		800		800		200		200	ns
CE Setup Time	t <sub>su(CE)</sub>		100		100		100		100		ns
CE Hold Time	t <sub>h(CE)</sub>		500		300		200		200		ns
CE Recovery Time	t <sub>rec(CE)</sub>		400		300		200		200		ns
CE Pulse Width	t <sub>w(CE)</sub>	Measured after valid subaddress is received		0.49		0.49		0.49		0.49	s
Setup Time	t <sub>su</sub>	Setup time for SDI data	20		20		20		20		ns
Hold Time	t <sub>h</sub>	Hold time for SDI data	500		300		200		200		ns
SDO Read Delay Time	t <sub>d(R)SDO</sub>	Bus load = 50pF		1300		650		350		350	ns
SDO Disable Time	t <sub>dis(SDO)</sub>	No load value; bus will be held up by bus-capacitance; use RC time constant with application values		200		100		50		50	ns
Transition Time SDI to SDO	t <sub>t(SDI-SDO)</sub>	Prepare for 0s to avoid bus conflict	0		0		0		0		ns





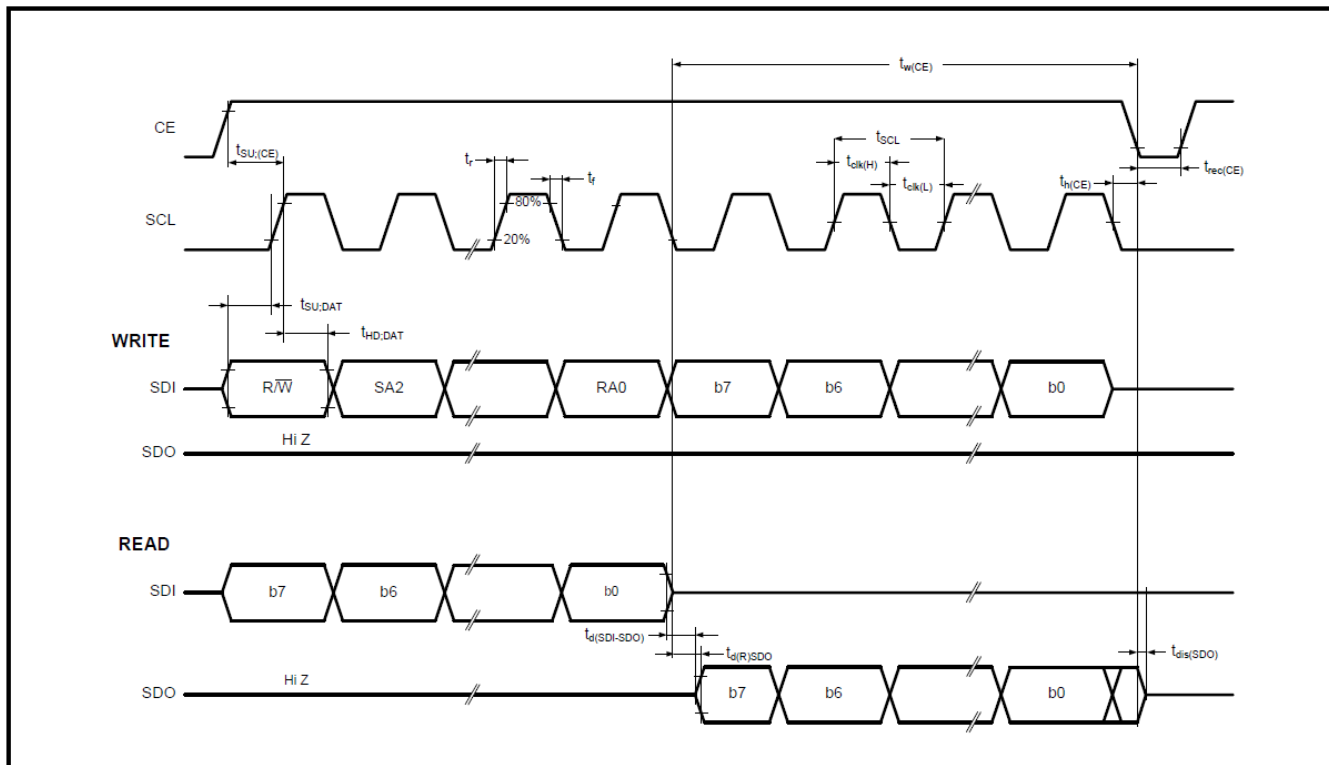
3.7 x 2.5 x 0.9 mm

AB-RTCMC-32.768kHz-EOA9-S3



RoHS/RoHS II compliant

## Interface Timing Characteristics



## PART IDENTIFICATION:

AB-RTCMC-32.768 kHz-EOA9-S3---

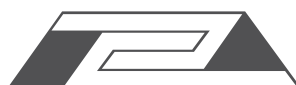
Operating Temp. Range
D: -40 ~ +85°C
H: -40 ~ +125°C

Timing Accuracy
A: see Table 1 below
B: see Table 1 below

Packaging
Blank: Bulk
T: 1000pcs/reel

Table 1. Time accuracy, DTCXO Digitally Temperature Compensated

Parameters		Min.	Typ.	Max.	Units
Time Accuracy Option: A	$T_{AMB}=+25^{\circ}\text{C}$		$\pm 1$	$\pm 3$	ppm
	$T_{AMB}=0 \sim +50^{\circ}\text{C}$		$\pm 2$	$\pm 4$	
	$T_{AMB}=-10 \sim +65^{\circ}\text{C}$		$\pm 3$	$\pm 5$	
	$T_{AMB}=-40 \sim +85^{\circ}\text{C}$		$\pm 4$	$\pm 6$	
	$T_{AMB}=-40 \sim +125^{\circ}\text{C}$		$\pm 5$	$\pm 8$	
Time Accuracy Option: B	$T_{AMB}=+25^{\circ}\text{C}$		$\pm 1$	$\pm 3$	ppm
	$T_{AMB}=0 \sim +50^{\circ}\text{C}$		$\pm 3$	$\pm 5$	
	$T_{AMB}=-10 \sim +65^{\circ}\text{C}$		$\pm 5$	$\pm 10$	
	$T_{AMB}=-40 \sim +85^{\circ}\text{C}$		$\pm 10$	$\pm 25$	
	$T_{AMB}=-40 \sim +125^{\circ}\text{C}$		$\pm 15$	$\pm 30$	

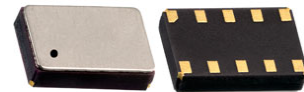


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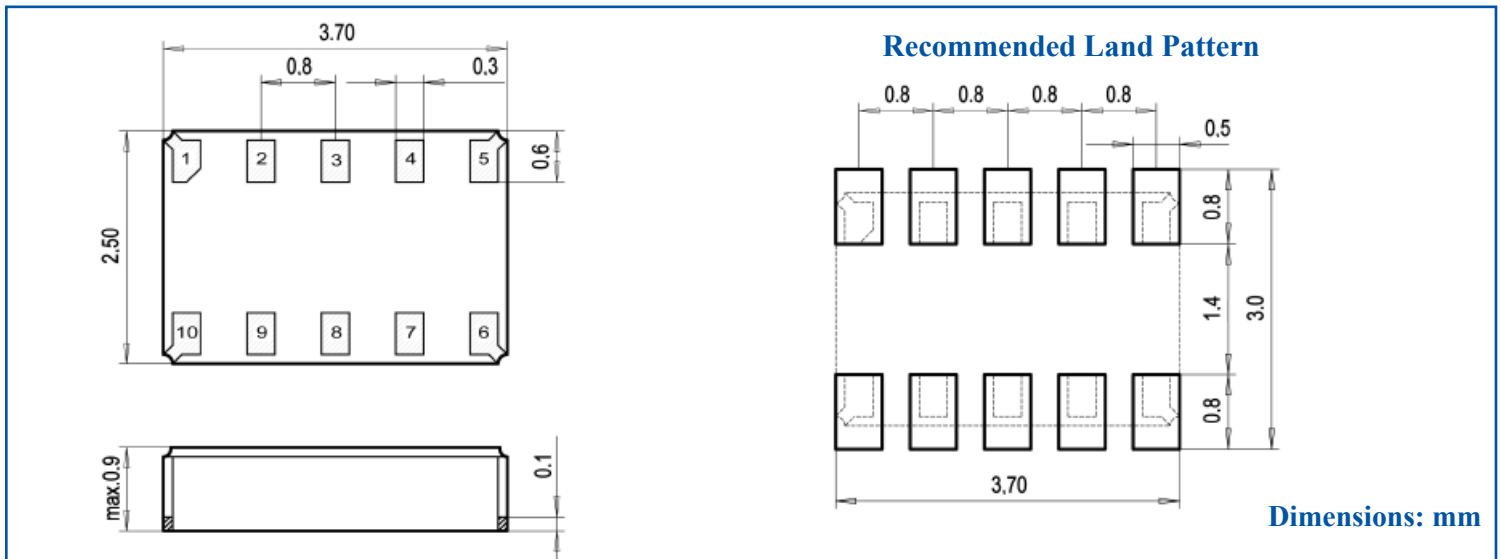


RoHS/RoHS II compliant



3.7 x 2.5 x 0.9 mm

## OUTLINE DIMENSIONS:



Dimensions: mm

## PIN DESCRIPTION:

Pin No.	Pin Name	Function
1	CLKOE	CLKOUT enable/disable pin; enable is active HIGH; tie to GND when not using CLKOUT
2	V <sub>DD</sub>	Positive supply voltage; positive or negative steps in supply voltage may affect oscillator performance, recommend 10 nF decoupling capacitor close to device
3	CLKOUT	Clock Output pin; CLKOUT or $\overline{\text{INT}}$ function can be selected.(Control_1; bit7; Clk/Int) CLKOUT output push-pull / $\overline{\text{INT}}$ function open-drain requiring pull-up resistor
4	SCL	Serial Clock Input pin; may float when CE inactive
5	SDO	Serial Data Output pin; push-pull; high-impedance when not driving; can be connected to SDI for single-wire data line.
6	V <sub>SS</sub>	Ground
7	$\overline{\text{INT}}$	Interrupt output pin; open-drain; active LOW
8	CE	Chip Enable input; active HIGH
9	V <sub>BACKUP</sub>	Backup Supply Voltage; tie to GND when not using backup supply voltage
10	SDI	Serial Data Input pin; may float when CE inactive

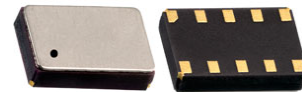


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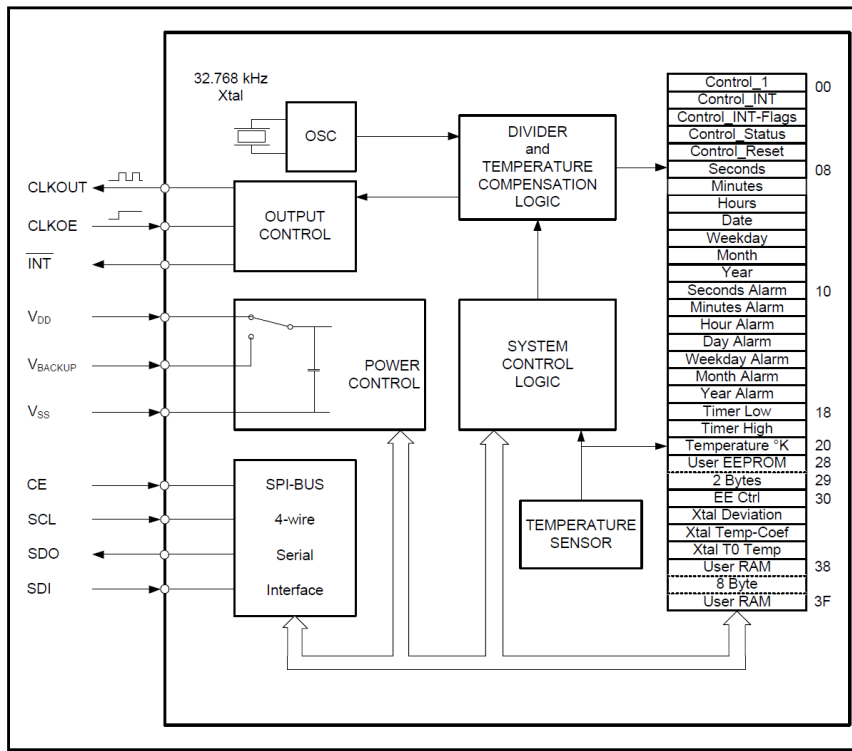


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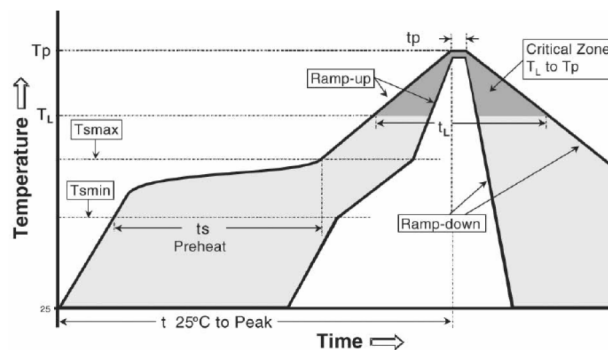
3.7 x 2.5 x 0.9 mm

## BLOCK DIAGRAM:



## RECOMMENDED REFLOW PROFILE:

Maximum Reflow Conditions in accordance with IPC/JEDEC J-STD-020C "Pb-free"



Temperature	Conditions	Units
Average Ramp-up Rate ( $T_{Smin}$ to $T_P$ )	3°C/second max	°C/s
Ramp Down Rate ( $T_{cool}$ )	6°C/second max	°C/s
Time 25°C to Peak Temperature ( $T_{to-peak}$ )	8 minutes max	m
<b>Preheat</b>		
Temperature Min ( $T_{Smin}$ )	150	°C
Temperature Max ( $T_{Smax}$ )	200	°C
Time $T_{Smin}$ to $T_{Smax}$ ( $t_s$ )	60 ~ 180	sec
<b>Time Above Liquidus</b>		
Temperature Liquidus ( $T_L$ )	217	°C
Time above Liquidus ( $t_L$ )	60 ~ 150	sec
<b>Peak Temperature</b>		
Peak Temperature ( $T_P$ )	260	°C
Time within 5°C of Peak Temperature ( $t_p$ )	20 ~ 40	sec

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CERTIFIED



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- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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